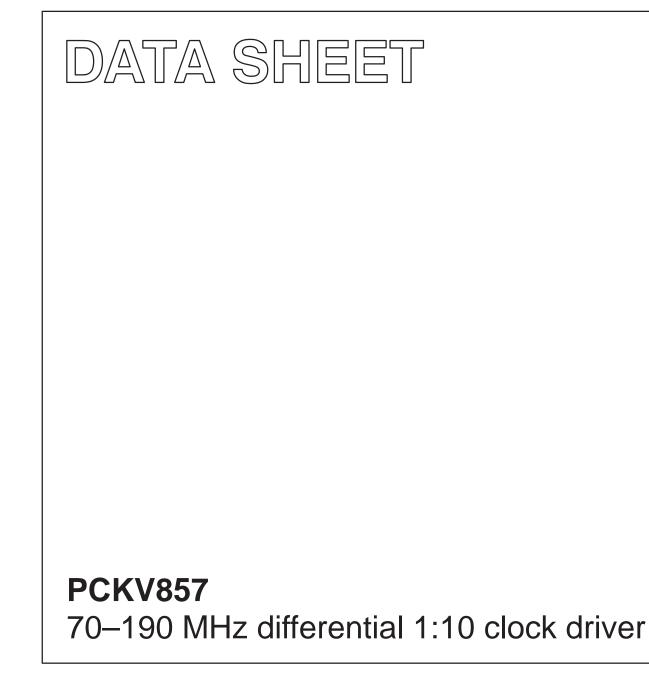
INTEGRATED CIRCUITS



Product data Supersedes data of 2001 Mar 16 File under Intergrated Circuits ICL03 2001 Jun 12



FEATURES

PCKV857

70–190 MHz differential 1:10 clock driver

PIN CONFIGURATION

Protection exceeds 2000 V to HBM per method A114. Latch-up testing is done to JEDEC Standard JESD78 which exceeds 100 mA

• ESD classification testing is done to JEDEC Standard JESD22.

- Optimized for clock distribution in DDR (Double Data Rate) SDRAM applications as per JEDEC specifications
- 1-to-10 differential clock distribution
- Very low skew (< 100 ps) and jitter (< 100 ps)
- Operation from 2.2 V to 2.7 V AV_{DD} and 2.3 V to 2.7 V V_{DD}
- SSTL_2 interface clock inputs and outputs
- CMOS control signal input
- Test mode enables buffers while disabling PLL
- Low current power-down mode
- Tolerant of Spread Spectrum input clock
- Full DDR solution provided when used with SSTL16877 or SSTV16857
- See PCKV856 for I²C capable clock driver

DESCRIPTION

The PCKV857 is a high-performance, low-skew, low-jitter zero delay buffer designed for 2.5 V V_{DD} and 2.5 V AV_{DD} operation and differential data input and output levels.

The PCKV857 is a zero delay buffer that distributes a differential clock input pair (CLK, CLK) to ten differential pairs of clock outputs (Y[0:9], $\overline{Y[0:9]}$) and one differential pair feedback clock outputs (FB_{OUT}, \overline{FB}_{OUT}). The clock outputs are controlled by the clock inputs (CLK, CLK), the feedback clocks (FB_{IN}, \overline{FB}_{IN}), and the analog power input (AV_{DD}). When PWRDWN is high, the outputs switch in phase and frequency with CLK. When PWRDWN is low, all outputs are disabled to high impedance state (3-State), and the PLL is shut down (low power mode). The device also enters the low power mode when the input frequency falls below 20 MHz. An input frequency detection circuit will detect the low frequency condition and after applying a > 20 MHz input signal, the detection circuit turns on the PLL again and enables the outputs.

When AV_{DD} is grounded, the PLL is turned off and bypassed for test purposes. The PCKV857 is also able to track spread spectrum clocking for reduced EMI.

The PCKV857 is characterized for operation from 0 to +70 °C.

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	TEMPERATURE RANGE ORDER CODE	
48-Pin Plastic TSSOP	0 to +70 °C	PCKV857DGG	SOT362-1

GND 1 70 2 Y0 3 V _{DDQ} 4 Y1 5 71 6 GND 7 GND 8 72 9 Y2 10 V _{DDQ} 11 V _{DDQ} 12 CLK 13 CLK 14 V _{DDQ} 15 AV _{DD} 16	8 47 49 49 49 49 49 49 49 49 49 49 49 49 49	FBIN VDDQ FBOUT
GND 8	41	GND
	40	Ÿ ₇
		Y ₇
V _{DDQ} 11		V _{DDQ}
	37	
CLK 13	36	
	35	FBIN
	34	
		FB _{OUT}
AGND 17	32	FB _{OUT}
GND 18	31	GND
Y ₃ 19	30	Υ ₈
Y ₃ 20	29	Y ₈
V _{DDQ} 21	28	V _{DDQ}
Y ₄ 22	27	Y ₉
¥4 23	26	-
GND 24	25	GND
		SW00691

PIN DESCRIPTION

PINS	SYMBOL	DESCRIPTION
1, 7, 8, 18, 24, 25, 31, 41, 42, 48	GND	SSTL_2 ground pins
2, 3, 5, 6, 9, 10, 19, 20, 22, 23, 26, 27, 29, 30, 32, 33, 39, 40, 43, 44, 46, 47	$Y_n, \overline{Y}_n, FB_{OUT}, \overline{FB_{OUT}}$	SSTL_2 differential outputs
4, 11, 12, 15, 21, 28, 34, 38, 46	V _{DDQ}	SSTL_2 power pins
13, 14, 35, 36	CLK _{IN} , CLK _{IN} , FB _{IN} , FB _{IN}	SSTL_2 differential inputs
16	AV _{DD}	Analog power
17	AGND	Analog ground
37	PWRDWN	Power-down control input

FUNCTION TABLE

INPUTS			OUTPUTS				PLL ON/OFF	
PWRDWN	CLK	CLK	Yn	Ϋ́n	FB _{OUT}	FB _{OUT}	FLL ON/OFF	
L	L	Н	Z	Z	Z ¹	Z ¹	OFF	
L	Н	L	Z	Z	Z ¹	Z ¹	OFF	
Н	L	Н	L	Н	L	Н	ON	
Н	Н	L	Н	L	Н	L	ON	
X2	< 20 MHz	< 20 MHz	Z	Z	Z ¹	Z ¹	OFF	

NOTES:

H = HIGH voltage level

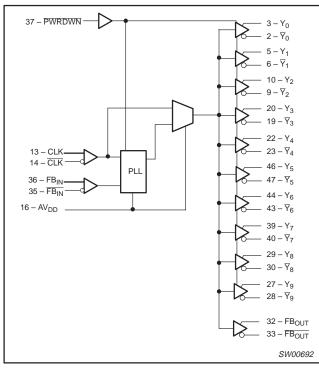
L = LOW voltage level

Z = high impedance OFF-state

X = don't care

Subject to change. May cause conflict with FB_{IN} pins.
 Additional feature that senses when the clock input is less than 20 MHz and places the part in sleep mode.

BLOCK DIAGRAM



2001 Jun 12

ABSOLUTE MAXIMUM RATINGS¹

SYMBOL	PARAMETER	CONDITION	LIN	UNIT	
STWBUL	PARAMETER	CONDITION	MIN	MAX	
V _{DDQ}	Supply voltage range		0.5	3.6	V
AV _{DD}	Supply voltage range		0.5	3.6	V
VI	Input voltage range	see Notes 2 and 3	-0.5	$V_{DDQ} + 0.5$	V
Vo	Output voltage range	see Notes 2 and 3	-0.5	$V_{DDQ} + 0.5$	V
I _{IK}	Input clamp current	$V_{I} < 0 \text{ or } V_{I} > V_{DDQ}$	—	±50	mA
I _{OK}	Output clamp current	V_{O} < 0 or V_{O} > V_{DDQ}	—	±50	mA
Ι _Ο	Continuous output current	$V_{O} = 0$ to V_{DDQ}	—	±50	mA
	Continuous current to GND or V_{DDQ}		_	±100	mA
T _{stg}	Storage temperature range		-65	+150	°C

NOTES:

 Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

3. This value is limited to 3.6 V maximum.

RECOMMENDED OPERATING CONDITIONS¹

OVMDOL	DADAMETED		CONDITION			UNIT	
SYMBOL	PARAMETER			MIN	TYP	МАХ	UNIT
V _{DDQ}	Supply voltage range			2.3	—	2.7	V
AV _{DD}	Supply voltage range			2.2	—	2.7	V
VIL	Low level input voltage	CLK, <u>CLK,</u> FB _{IN} , FB _{IN}		—	_	V _{DDQ} /2 - 0.18	V
		PWRDWN		-0.3	—	0.7	
VIH	High level input voltage	CLK, <u>CLK,</u> FB _{IN} , FB _{IN}		V _{DDQ} /2 + 0.18	_	—	V
		PWRDWN		1.7	—	$V_{DDQ} + 0.3$	
	DC input signal voltage		Note 2	-0.3	—	V _{DDQ}	V
M	DC differential input signal voltage	CLK, FB _{IN}	Note 3	0.36	—	V _{DDQ} + 0.6	V
V _{ID}	AC differential input signal voltage	CLK, FB _{IN}	Note 3	0.7	—	V _{DDQ} + 0.6	V
V _{OX}	Output differential cross-voltage		Note 4	$V_{DDQ}/2 - 0.2$	V _{DDQ} /2	$V_{DDQ}/2 + 0.2$	V
V _{IX}	Input differential cross-voltage		Note 4	$V_{DDQ}/2 - 0.2$	—	$V_{DDQ}/2 + 0.2$	V
I _{OH}	High-level output current			—	—	-12	mA
I _{OL}	Low-level output current			—	_	12	mA
SR	Input slew rate			1	—	4	V/ns
T _{amb}	Operating free-air temperature			0	—	70	°C

NOTES:

1. Unused inputs must be held high or low to prevent them from floating.

2. DC input signal voltage specifies the allowable DC execution of differential input.

 Differential input signal voltage specifies the differential voltage |VTR – VCP| required for switching, where VTR is the true input level and VCP is the complementary input level.

4. Differential cross-point voltage is expected to track variations of V_{CC} and is the voltage at which the differential signals must be crossing.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

		TEAT CONDITIONS				
SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IK}	Input voltage, all inputs	V _{DDQ} = 2.3 V, I _I = -18 mA	—	—	-1.2	V
M		V_{DDQ} = min to max, I_{OH} = -1 mA	V _{DDQ} – 0.1	—	—	V
V _{OH}	High-level output voltage	$V_{DDQ} = 2.3 \text{ V}, I_{OH} = -12 \text{ mA}$	1.7	—	—	V
M		V_{DDQ} = min to max, I_{OL} = 1 mA	—	—	0.1	V
V _{OL}	Low-level output voltage	V _{DDQ} = 2.3 V, I _{OL} = 12 mA	—	—	0.6	V
I _I	Input current	$V_{DDQ} = 2.7 \text{ V}, \text{ V}_{I} = 0 \text{ V} \text{ to } 2.7 \text{ V}$	—	—	±10	μΑ
I _{OZ}	High-impedance-state output current	$V_{DDQ} = 2.7 \text{ V}, V_O = V_{DDQ} \text{ or GND}$	—	—	±10	μΑ
I _{DDPD}	Power-down current on V _{DDQ} + AV _{DD}	CLK and $\overline{\text{CLK}} = 0 \text{ MHz},$ $\overline{\text{PWRDWN}} = \text{low};$ $\Sigma \text{ of } \text{I}_{\text{DD}} \text{ and } \text{AI}_{\text{DD}}$	_	30	100	μA
I _{DD}	Dynamic current on V _{DDQ}	f _O = 67 MHz to 190 MHz	—	200	300	mA
AI _{DD}	Supply current on AV _{DD}	$f_O = 67 \text{ MHz}$ to 190 MHz	—	8	10	mA
CI	Input capacitance	V_{CC} = 2.5 V, V_{I} = V_{CC} or GND	2	2.8	3	рF

NOTE:

This is intended to operate in the SSTL_2 type IV unterminated mode without series resistors on the outputs.
 All typical values are at respective nominal V_{DDQ}.

3. Differential cross-point voltage is expected to track variations of V_{DDQ} and is the voltage at which the differential signals must be crossing.

TIMING REQUIREMENTS

Over recommended ranges of supply voltage and operating free-air temperature.

SYMBOL	PARAMETER	MIN	MAX	UNIT
f _{CK}	Operating clock frequency	60	190	MHz
	Input clock duty cycle	40	60	%
	Stabilization time ¹	100	—	μs

NOTE:

1. Time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal after power-up.

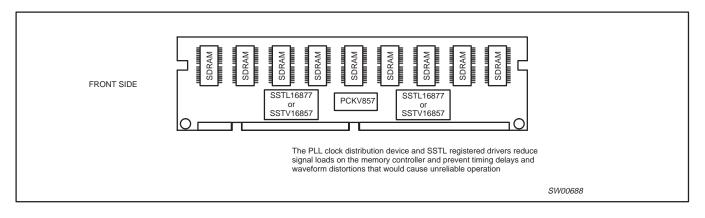
AC CHARACTERISTICS

GND = 0 V; t_r = t_f \leq 2.5 ns; CL = 50 pF; RL = 1 $k\Omega$

SYMBOL	DADAMETED		CONDITION				
STMBOL	PARAMETER	WAVEFORM	CONDITION	MIN	TYP	MAX	UNIT
t _(O)	Static phase offset	Figure 1		-150	0	150	ps
t _{SK(O)}	Output clock skew	Figure 2		_	—	75	ps
t _{SLR(O)}	Output clock skew rate	Figure 3		1	—	2	V/ns
t _{JIT(PER)}	Jitter (period)	Figure 4	$f_{O} = 67 \text{ MHz} \text{ to } 200 \text{ MHz}$	-75	—	75	ps
tJIT(CC)	Jitter (cycle-to-cycle)	Figure 5	f_{O} = 67 MHz to 200 MHz	-75	—	75	ps
tJIT(HPER)	Half-period jitter	Figure 6		-100	-	100	ps
t _{PLH} 1	Low to high level propagation delay		Test mode/CLK to any output	_	3.7	_	ns
t _{PHL} 1	High to low level propagation delay		Test mode/CLK to any output	_	3.7	_	ns

NOTE:

1. Refers to transition of noninverting output.



AC WAVEFORMS

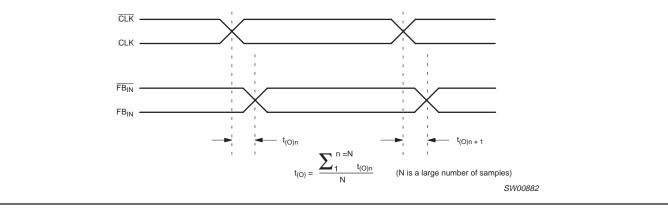


Figure 1. Static phase offset

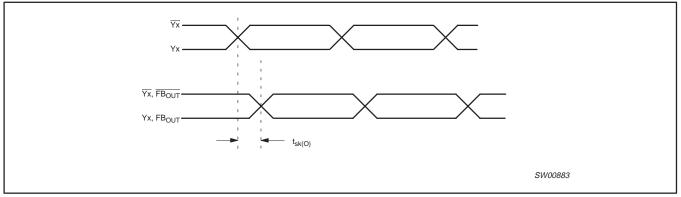


Figure 2. Output skew

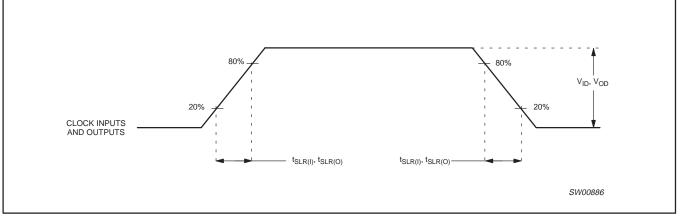


Figure 3. Input and output slew rates

Product data

70-190 MHz differential 1:10 clock driver

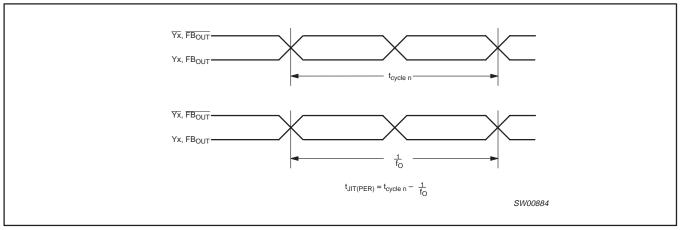


Figure 4. Period jitter

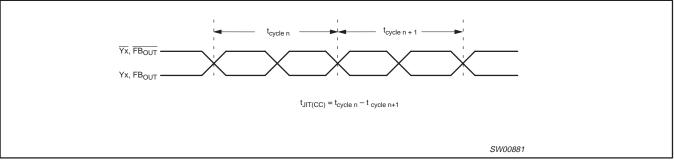


Figure 5. Cycle-to-cycle jitter

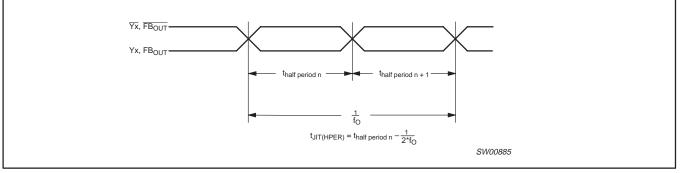


Figure 6. Half-period jitter

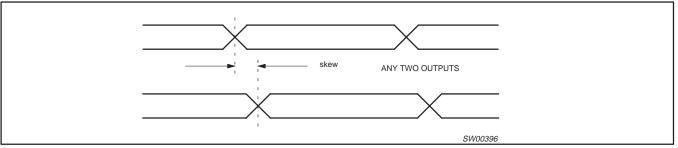


Figure 7. Skew between any two outputs.

PCKV857

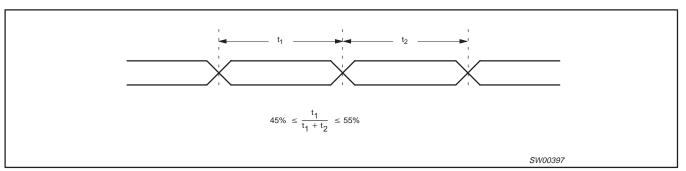


Figure 8. Duty cycle limits and measurement

TEST CIRCUIT

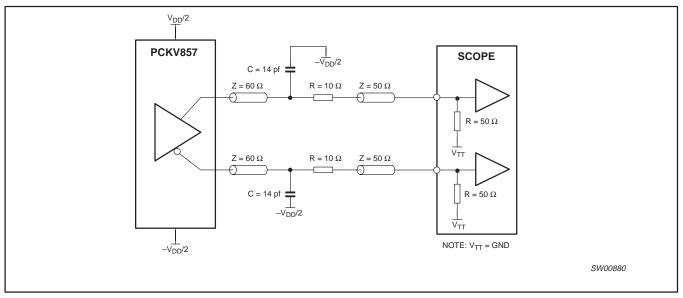
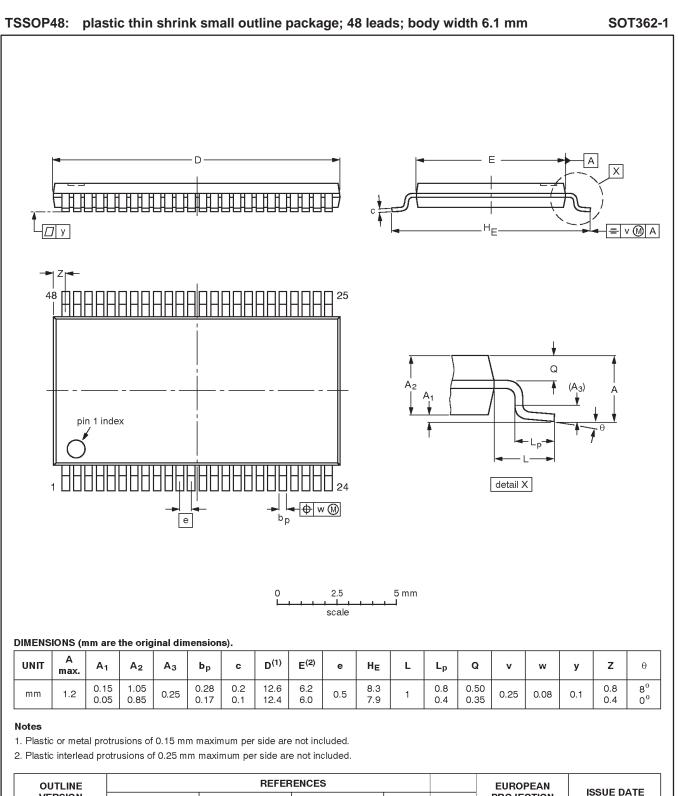


Figure 9. Output load test circuit



2001 Jun 12

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Product data

PCKV857

NOTES

PCKV857

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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